



74VHC112 Dual J-K Flip-Flops with Preset and Clear

Features

- High speed: f_{MAX} = 200MHz (Typ.) at V_{CC} = 5.0V
- Low power dissipation: $I_{CC} = 2\mu A$ (Max.) at $T_A = 25$ °C
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (Min.)
- Power down protection is provided on all inputs
- Pin and function compatible with 74HC112

General Description

The VHC112 is an advanced high speed CMOS device fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The VHC112 contains two independent, high-speed JK flip-flops with Direct Set and Clear inputs. Synchronous state changes are initiated by the falling edge of the clock. Triggering occurs at a voltage level of the clock and is not directly related to transition time. The J and K inputs can change when the clock is in either state without affecting the flip-flop, provided that they are in the desired state during the recommended setup and hold times relative to the falling edge of the clock. The LOW signal on PR or CLR prevents clocking and forces Q and $\overline{\rm Q}$ HIGH, respectively. Simultaneous LOW signals on PR and CLR force both Q and $\overline{\rm Q}$ HIGH.

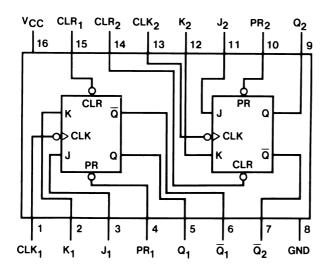
An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.



Order Number	Package Number	Package Description
74VHC112M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74VHC112SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC112MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering number.

Connection Diagram



Pin Description

Pin Names	Description
J ₁ , J ₂ , K ₁ , K ₂	Data Inputs
CLK ₁ , CLK ₂	Clock Pulse Inputs (Active Falling Edge)
CLR ₁ , CLR ₂	Direct Clear Inputs (Active LOW)
PR ₁ , PR ₂	Direct Preset Inputs (Active LOW)
$Q_1, Q_2, \overline{Q}_1, \overline{Q}_2$	Outputs

Truth Table

	Ir	Out	outs			
PR	CLR	CP	J	K	Q	Q
L	Н	Х	Х	Х	Н	L
Н	L	Х	Х	Х	L	Н
L	L	Х	Х	Х	Н	Н
Н	Н	~	h	h	\overline{Q}_0	Q_0
Н	Н	~	I	h	L	Н
Н	Н	~	h	I	Н	L
Н	Н	~	I	I	Q_0	\overline{Q}_0

H (h) = HIGH Voltage Level

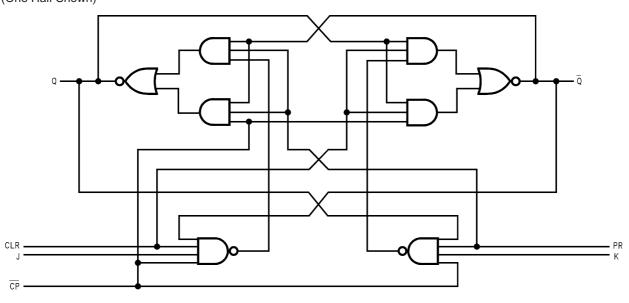
L (I) = LOW Voltage Level

X = Immaterial

 $\begin{aligned} &\mathbf{Q}_0 \ (\overline{\mathbf{Q}}_0) = \text{Before HIGH-to-LOW Transition of Clock} \\ &\text{Lower case letters indicate the state of the referenced} \\ &\text{input or output one setup time prior to the HIGH-to-LOW} \\ &\text{clock transition.} \end{aligned}$



(One Half Shown)



Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	-0.5V to +7.0V
V _{IN}	DC Input Voltage	–0.5V to +7.0V
V _{OUT}	DC Output Voltage	–0.5V to V _{CC} + 0.5V
I _{IK}	Input Diode Current	–20mA
I _{OK}	Output Diode Current	±20mA
I _{OUT}	DC Output Current	±25mA
I _{CC}	DC V _{CC} /GND Current	±50mA
T _{STG}	Storage Temperature	–65°C to +150°C
T _L	Lead Temperature (Soldering, 10 seconds)	260°C

Recommended Operating Conditions⁽¹⁾

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	2.0V to +5.5V
V _{IN}	Input Voltage	0V to +5.5V
V _{OUT}	Output Voltage	0V to V _{CC}
T _{OPR}	Operating Temperature	–40°C to +85°C
t _r , t _f	Input Rise and Fall Time,	
	$V_{CC} = 3.3V \pm 0.3V$	0ns/V ~ 100ns/V
	$V_{CC} = 5.0V \pm 0.5V$	0ns/V ~ 20ns/V

Note:

1. Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

					1	T _A = 25°	C		40°C to 5°C	
Symbol	Parameter	V _{CC} (V)	Con	Conditions		Тур.	Max.	Min.	Max.	Units
V _{IH}	HIGH Level Input	2.0			1.50			1.50		V
	Voltage	3.0-5.5			0.7 x V _{CC}			0.7 x V _{CC}		
V _{IL}	LOW Level Input	2.0					0.50		0.50	V
	Voltage	3.0-5.5					0.3 x V _{CC}		0.3 x V _{CC}	
V _{OH}	HIGH Level	2.0	$V_{IN} = V_{IH}$	$V_{IN} = V_{IH}$ $I_{OH} = -50\mu A$		2.0		1.9		V
	Output Voltage	3.0	or V _{IL}		2.9	3.0		2.9		
		4.5			4.4	4.5		4.4		
		3.0		$I_{OH} = -4mA$	2.58			2.48		
		4.5		$I_{OH} = -8mA$	3.94			3.80		
V _{OL}	LOW Level	2.0	$V_{IN} = V_{IH}$	$I_{OL} = 50\mu A$		0.0	0.1		0.1	V
	Output Voltage	3.0	or V _{IL}			0.0	0.1		0.1	
		4.5				0.0	0.1		0.1	
		3.0		I _{OL} = 4mA			0.36		0.44	
		4.5		I _{OL} = 8mA	3	6 34	0.36		0.44	
I _{IN}	Input Leakage Current	0–5.5	V _{IN} = 5.5V or GND		36 3	3	±0.1		±1.0	μΑ
I _{cc}	Quiescent Supply Current	5.5	$V_{IN} = V_{CC}$	V _{IN} = V _{CC} or GND		3.	2.0		20.0	μA

AC Electrical Characteristics

				T _A = 25°C		T _A = -40°C to +85°C			
Symbol	Parameter	V _{CC} (V)	Conditions	Min.	Тур.	Max.	Min.	Max.	Units
f _{MAX}	Maximum Clock	3.3 ± 0.3	C _L = 15pF	110	150		100		MHz
	Frequency		C _L = 50pF	90	120		80		
		5.0 ± 0.5	C _L = 15pF	150	200		135		MHz
			C _L = 50pF	120	185		110		
t _{PLH} , t _{PHL}	Propagation Delay Time	3.3 ± 0.3	C _L = 15pF		8.5	11.0	1.0	13.4	ns
	(CP to Q_n or \overline{Q}_n)		$C_L = 50pF$		10.0	15.0	1.0	16.5	
		5.0 ± 0.5	C _L = 15pF		5.1	7.3	1.0	8.8	ns
			$C_L = 50pF$		6.3	10.5	1.0	12.0	
t _{PLH} , t _{PHL}	Propagation Delay Time	3.3 ± 0.3	C _L = 15pF		6.7	10.2	1.0	11.7	ns
	(PR or CLR to Q_n or \overline{Q}_n)		$C_L = 50pF$		9.7	13.5	1.0	15.0	
		5.0 ± 0.5	C _L = 15pF		4.6	6.7	1.0	8.0	ns
			$C_L = 50pF$		6.4	9.5	1.0	11.0	
C _{IN}	Input Capacitance		V _{CC} = Open	A 30	4	10		10	pF
C _{PD}	Power Dissipation Capacitance		(2)	200	18				pF

Note:

2. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained from the equation: I_{CC} (opr.) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CG} / 4$ (per F/F), and the total C_{PD} when n pcs of the Flip-Flop operate can be calculated by the following equation: C_{PD} (total) = 30 + 14 \cdot n

AC Operating Requirements

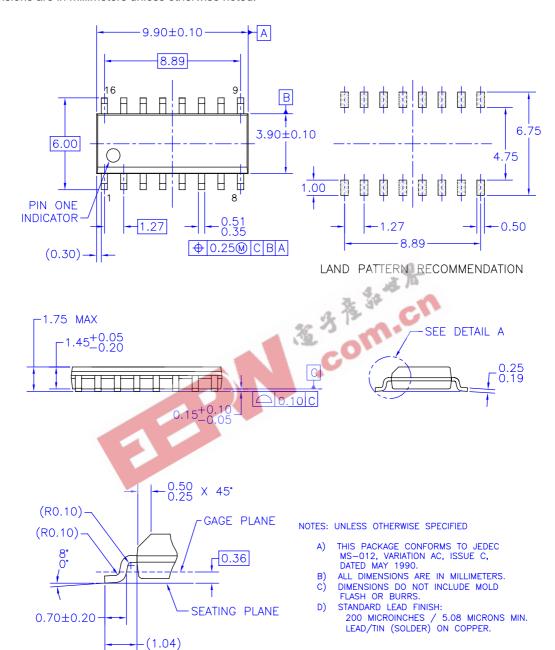
			T _A =	25°C	T _A = -40°C to +85°C	
Symbol	Parameter	V _{CC} (V) ⁽³⁾	Тур.	Gua	aranteed Minimum	Units
t _W	Minimum Pulse Width	3.3		5.0	5.0	ns
	(CP or CLR or PR)	5.0		5.0	5.0	
t _S	Minimum Setup Time	3.3		5.0	5.0	ns
	(J _n or K _n to CP _n)	5.0		4.0	4.0	
t _H	Minimum Hold Time	3.3		1.0	1.0	ns
	$(J_n \text{ or } K_n \text{ to } CP_n)$	5.0		1.0	1.0	
t _{REC}	Minimum Recovery Time	3.3		6.0	6.0	ns
	(CLR or PR to CP)			5.0	5.0	

Note:

3. V_{CC} is 3.3 ± 0.3V or 5.0 ± 0.5V.

Physical Dimensions

Dimensions are in millimeters unless otherwise noted.



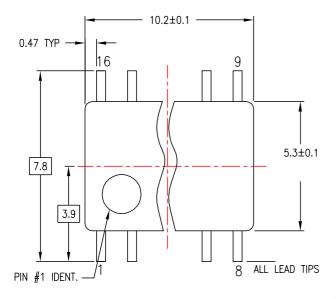
M16AREVK

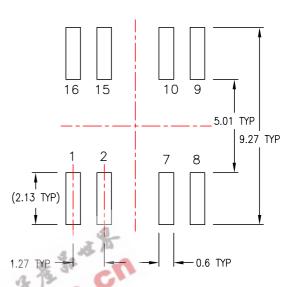
DETAIL A

Figure 1. 16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Package Number M16A

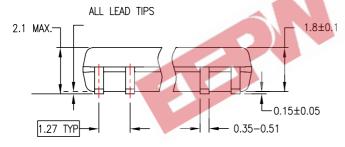
Physical Dimensions (Continued)

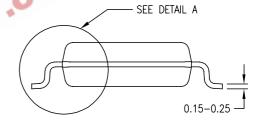
Dimensions are in millimeters unless otherwise noted.





AND PATTERN RECOMMENDATION

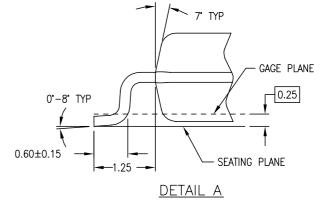




DIMENSIONS ARE IN MILLIMETERS

NOTES:

- A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.
 B. DIMENSIONS ARE IN MILLIMETERS.
 C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.



M16DREVC

Figure 2. 16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide Package Number M16D

Physical Dimensions (Continued) Dimensions are in millimeters unless otherwise noted. 5.00±0.10 4.55 5.90 4.45 7.35 В 6.4 4.4±0.1 3.2 O.2 CBA ALL LEAD TIPS PIN #1 IDENT. LAND PATTERN RECOMMENDATION (F) 0.11-SEE DETAIL A ALL LEAD TIPS 1.1 MAX ◯ 0.1 C -C-

NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB,

0.19 - 0.30

⊕ 0.10
 M A B
 □
 C
 □

- B. DIMENSIONS ARE IN MILLIMETERS
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS
- D. DIMENSIONING AND TOLERANCES PER ANSI Y14.5M, 1994
- E. DRAWING FILE NAME: MTC16REV4

0.65

F. LAND PATTERN RECOMMENDATION PER IPC7351 - ID# TSOP65P640X110-16N

MTC16rev4

Figure 3. 16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC16

0.6±0.1

DETAIL A

12° TOP AND BOTTOM

GAGE PLANE

0.25

SEATING PLANE





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